

I-V Characteristic of a pn Diode

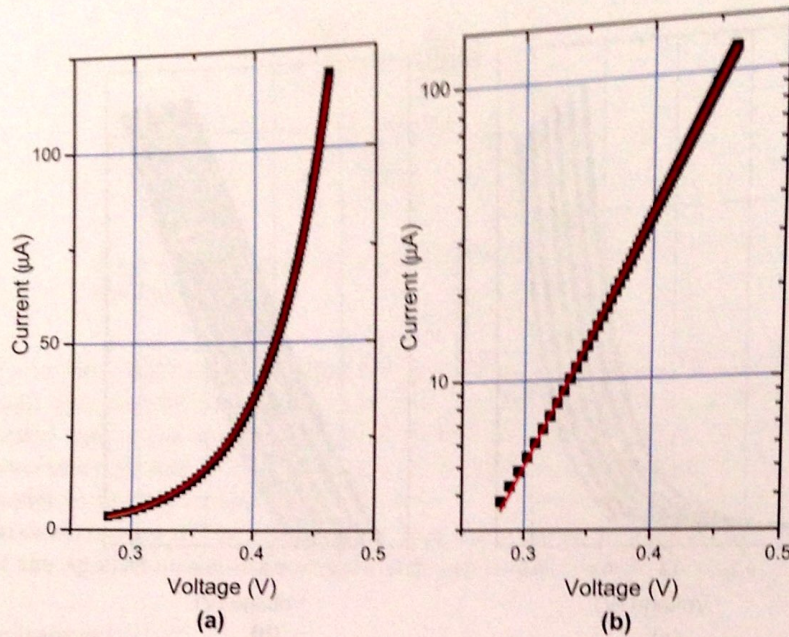


Figure 4. Exponential fit of data corresponding to the temperature $T = 47.8 \pm 0.2$ °C in linear scale (a) and semi-logarithmic scale (b). Normalized χ^2 is of the order of unity for uncertainties of the current of the order of $0.05 \mu A$ which is three times larger than the instrumental resolution and can be attributed to the experimental variability.

exponential dependence of I on V . A first analysis of data can be done by using eq. (1), limiting the measurements to the region of moderate injection current where I is dominated by diffusion. Consequently, we can neglect non-linear effects on the current, reducing the number of parameters to the two appearing in eq. (1). We write the eq. (1) in the more compact form:

$$I = A [\exp(BV) - 1]$$

where $B = e/nkT$. Fig. 4a shows a non linear fit of this equation, through a standard least square routine[16], which gives a value of $B = e/nkT = 19.48 \pm 0.03 V^{-1}$, largely different from the ideal diode constant at the same temperature $T = 47.8 \pm 0.2^\circ C$ - $B_{id} = e/kT = 36.20 V^{-1}$. The agreement of the model with the data requires a value:

$$n = \frac{B_{id}}{B} = 1.86 \pm 0.01$$

which is lower than the value of the SPICE models for 1N4148[17] diode but agrees with other experiments [18], pointing out the variability of this parameter due to constructive tolerance or data analysis.

A different treatment of data, often met in the literature, considers the large value of the product BV in the range investigated. In this case, one can neglect the term -1 in the parenthesis and can take the natural logarithm of the measured current, finding:

$$\log I = \log A + BV$$